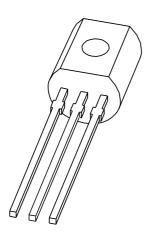
DISCRETE SEMICONDUCTORS

DATA SHEET



BFV421PNP high-voltage transistor

Product specification Supersedes data of 1999 Apr 23 2004 Nov 11





PNP high-voltage transistor

BFV421

FEATURES

- High voltage
- · High transition frequency
- Low output capacitance.

APPLICATIONS

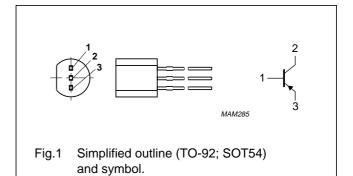
• Primarily intended for video applications (monitors).

DESCRIPTION

PNP transistor in a plastic TO-92; SOT54 package. NPN complement: BFV420.

PINNING

PIN	DESCRIPTION
1	base
2	collector
3	emitter



ORDERING INFORMATION

TYPE NUMBER		PACKAGE					
ITPE NOWIBER	NAME DESCRIPTION VERSION						
BFV421	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54				

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	-140	V
V _{CEO}	collector-emitter voltage	open base	_	-100	V
V _{EBO}	emitter-base voltage	open collector	_	-5	V
I _C	collector current (DC)		_	-100	mA
I _{CM}	peak collector current		_	-100	mA
I _{BM}	peak base current		_	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	_	830	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	ambient temperature		-65	+150	°C

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	in free air; note 1	150	K/W

Note

1. Transistor mounted on a printed-circuit board; maximum lead length 4 mm; mounting pad for collector lead minimum 10×10 mm.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	V _{CB} = -100 V; I _E = 0 A	_	-100	nA
		$V_{CB} = -100 \text{ V}; I_E = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$	_	-10	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -4 \text{ V}; I_C = 0 \text{ A}$	_	-100	nA
h _{FE}	DC current gain	V _{CE} = −10 V			
		$I_C = -10 \text{ mA}$	150	_	
		$I_C = -50 \text{ mA}$	20	_	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -30 \text{ mA}; I_B = -5 \text{ mA}$	_	-200	mV
C _{re}	feedback capacitance	$V_{CE} = -25 \text{ V}; I_C = i_c = 0 \text{ A}; f = 1 \text{ MHz}$	_	2.3	pF
f _T	transition frequency	$V_{CE} = -20 \text{ V; } I_{C} = -20 \text{ mA;}$ f = 100 MHz	150	_	MHz

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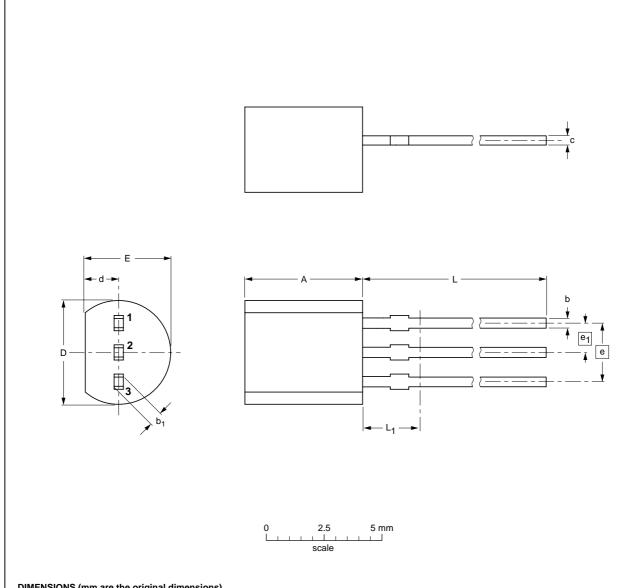
PNP high-voltage transistor

BFV421

PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b ₁	С	D	d	E	е	e ₁	L	L ₁ ⁽¹⁾ max.	
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5	

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA	PROJECTION		1330E DATE
SOT54		TO-92	SC-43A			97-02-28 04-06-28

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PNP high-voltage transistor

BFV421

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Notes

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- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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